Panasonic

DZ4J068K0R

Zener Diode DZ4J068K0R

Silicon epitaxial planar type

Unit: mm 2.0 For constant voltage / For surge absorption circuit <u>0. 3</u> 0 13 - -4 Features Excellent rising characteristics of zener current Iz 25 Low zener operating resistance Rz Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant) 2 1 0.7 Marking Symbol: GJ (0.65)(0.65) 1.3 Basic Part Number : Dual DZ2J068 (Parallel) Packaging 3. Cathode-2 1. Anode-1 Embossed type (Thermo-compression sealing) 3 000 pcs / reel (standard) 2. Anode-2 4. Cathode-1 Panasonic SMini4-F3-B Absolute Maximum Ratings Ta = 25 °C JEITA SC-113BB Symbol Rating Unit Code Parameter

Internal Connection	

Repetitive peak forward current IFRM 200 mΑ Total power dissipation PT 200 mW Electrostatic discharge ESD ±15 kV Junction temperature Ti 150 °C Operating ambient temperature Topr -40 to +85 °C °C Storage temperature Tstg -55 to +150

Note) *1: Mounted on glass epoxy print board. (45 mm x 45 mm x 1 mm) Solder in (0.8 mm x 0.8 mm)

*2: Test method:IEC61000_4_2(C = 150 pF,R = 330 Ω, Contact discharge:10 times)

Electrical Characteristics Ta = 25 °C ± 3 °C Parameter Symbol Conditions Min Тур Max Unit Forward voltage VF IF = 10 mA 1.0 V 1. *2 Zener voltage VZ IZ = 5 mA 6.46 7.14 V RZ IZ = 5 mA 20 Zener operating resistance Ω Zener rise operating resistance RZK IZ = 0.5 mA 60 Ω Reverse current IR VR = 4 V 0.1 μA Temperature coefficient of zener voltage SZ IZ = 5 mA 3.2 mV/°C

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

2. Absolute frequency of input and output is 5 MHz.

3. *1: The temperature must be controlled 25 °C for VZ mesurement. VZ value measured at other temperature must be adjusted to VZ (25 °C)

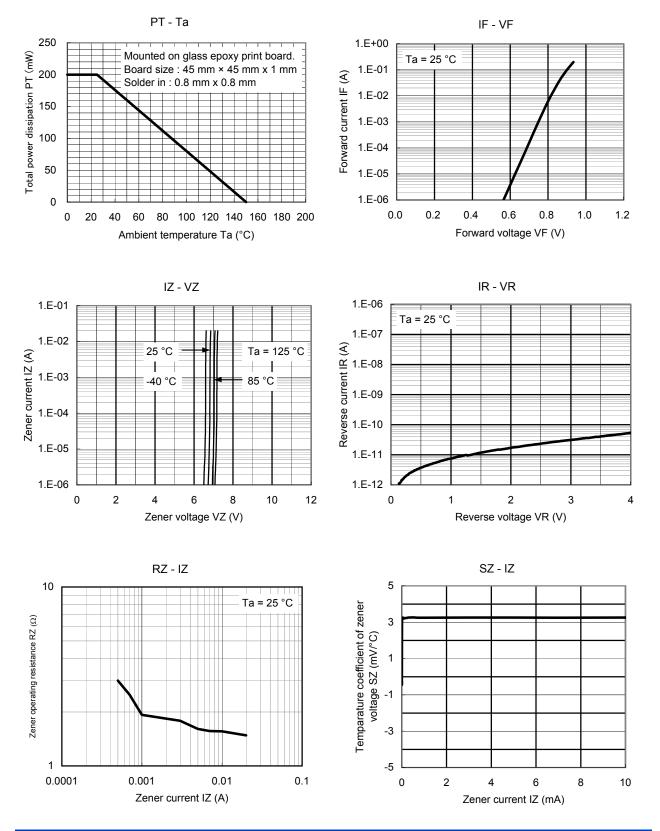
*2: VZ guaranted 20 ms after current flow.

*3: Tj = 25 °C to 150 °C



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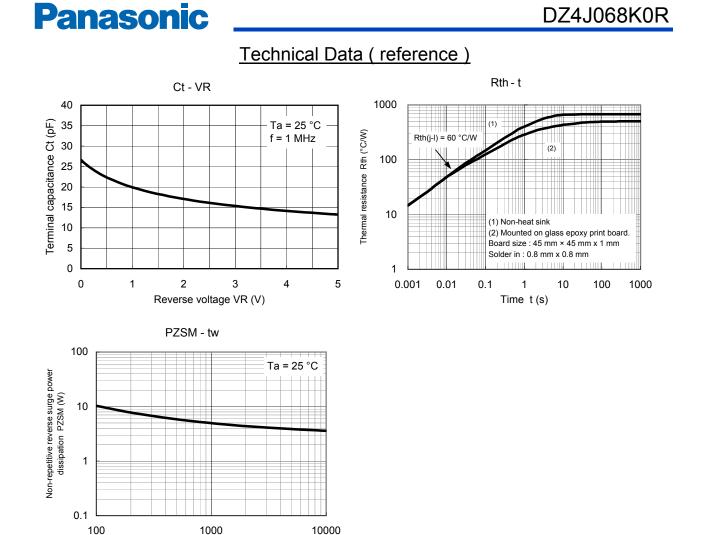
Technical Data (reference)



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Established : 2009-12-11 Revised : 2013-10-04

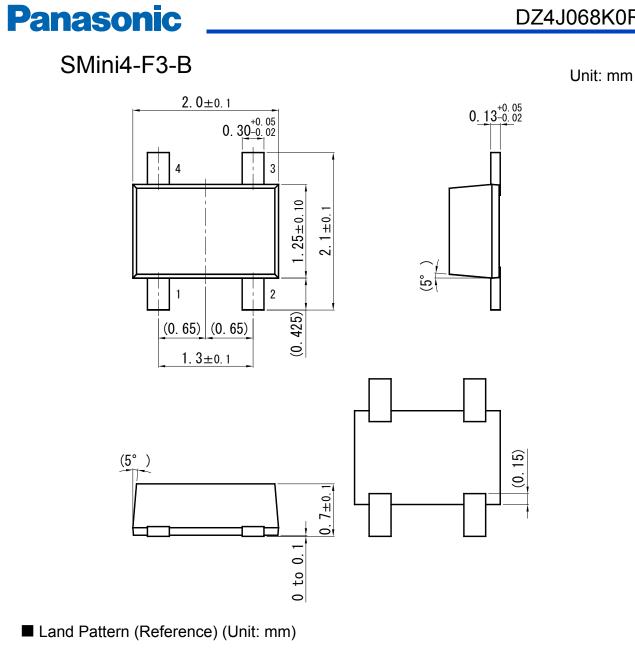
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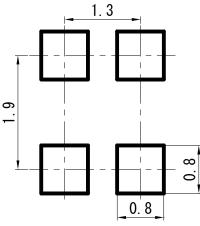


Zener Diode

Pulse width tw (µs)

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